Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-469-8571

### Inclosure Material:

Ceramic

## Overall Length:

Between 0.140 inches and 0.163 inches

# **Overall Diameter:**

Between 0.118 inches and 0.124 inches

#### **End Application:**

Aircraft, b-2 bomber (atb)

### **Mounting Facility Quantity:**

2

### **Mounting Method:**

Compression

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

120.0 breakover voltage, dc and 180.0 breakover voltage, dc

### Power Rating Per Characteristic:

10.0 watts small-signal input power, common-emitter absolute

## Maximum Operating Tempurature Per Measurement Point:

-55.0 degrees celsius case and 200.0 degrees celsius case

# Terminal Type And Quantity:

2 uninsulated wire lead

#### Shelf Life:

N/a

## Unit Of Measure:

---

#### Demilitarization:

No

#### Fiig:

A110a0